

**RS-232 LINE DRIVER/RECEIVER AT 3.3 V/5 V**

The  $\mu$ PD4721 is a high-breakdown voltage silicon gate CMOS line driver/receiver based on the EIA/TIA-232-E standard. The internal DC/DC converter can switch between multiple voltages, realizing the allowing it to operate with a single +3.3 V or +5 V power supply. It also provides standby function.

This IC incorporates 2 driver circuits and 2 receiver circuits. An RS-232 interface circuit can be easily configured by connecting 5 capacitors externally.

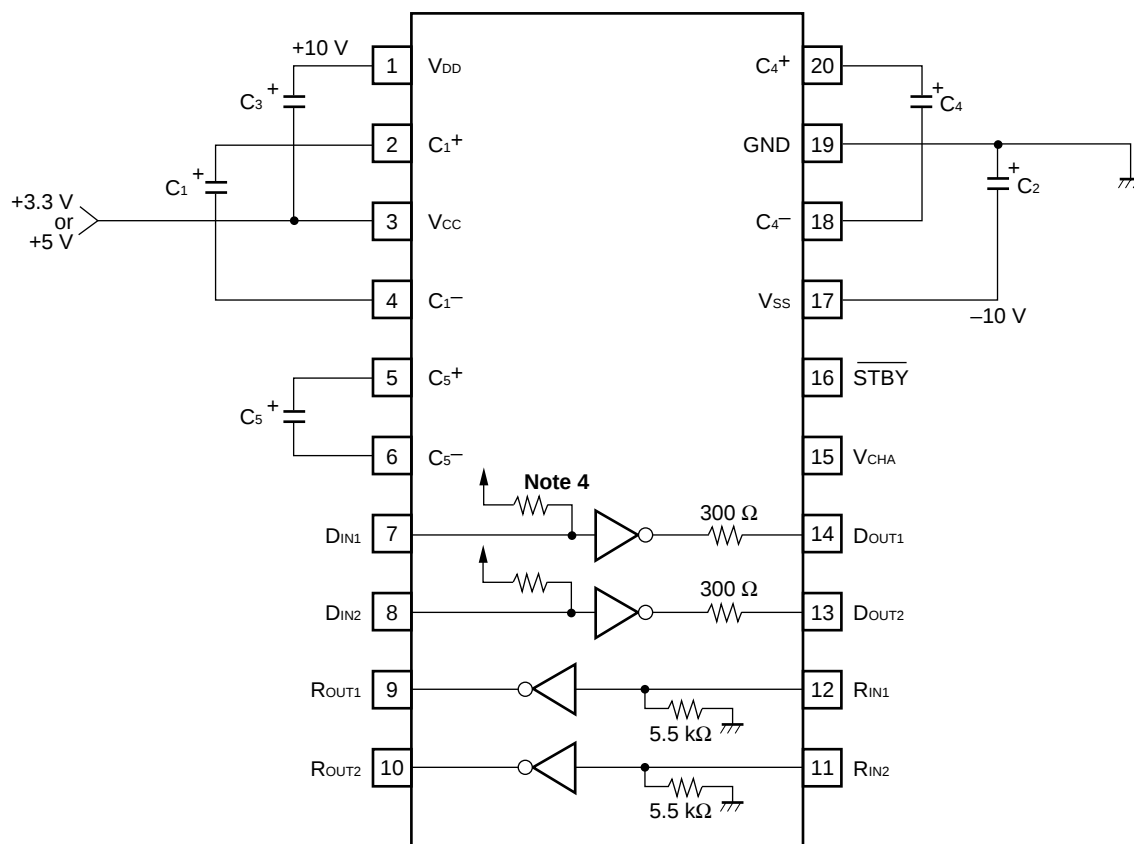
**FEATURES**

- Conforms to EIA/TIA-232-E (former name, RS-232C) standards
- Selectable +3.3 V/+5 V single power supply (selected by V<sub>CHA</sub> pin)
- By setting the standby pin to a low level (standby mode), circuit current can be reduced. At such times, the driver output is in a high-impedance state.

**ORDERING INFORMATION**

| Part number        | Package                       |
|--------------------|-------------------------------|
| $\mu$ PD4721GS-GJG | 20-pin plastic SSOP (300 mil) |

BLOCK DIAGRAM/PIN CONFIGURATION (Top View)



- Note 1.**  $V_{DD}$  and  $V_{SS}$  are output pins stepped up internally. These pins should not be loaded directly.
- 2.** Capacitors  $C_1$  to  $C_5$  with a breakdown voltage of 20 V or higher are recommended. And it is recommended to insert the capacitor that is 0.1  $\mu\text{F}$  to 1  $\mu\text{F}$  between  $V_{CC}$  and GND.
- 3.** If  $V_{CHA}$  is kept low level (in 5 V mode), capacitor  $C_5$  is not necessary.
- 4.** The pull-up resistors at driver input are active resistors.

## Truth Table

### Driver

| $\overline{\text{STBY}}$ | D <sub>IN</sub> | D <sub>OUT</sub> | Remarks                                   |
|--------------------------|-----------------|------------------|-------------------------------------------|
| L                        | ×               | Z                | Standby mode (DC/DC converter is stopped) |
| H                        | L               | H                | Space level output                        |
| H                        | H               | L                | Mark level output                         |

### Receiver

| $\overline{\text{STBY}}$ | R <sub>IN</sub> | R <sub>OUT</sub> | Remarks                                   |
|--------------------------|-----------------|------------------|-------------------------------------------|
| L                        | ×               | H                | Standby mode (DC/DC converter is stopped) |
| H                        | L               | H                | Mark level input                          |
| H                        | H               | L                | Space level input                         |

### 3 V ↔ 5 V switching Note 5

| V <sub>CHA</sub> | Operating mode             |
|------------------|----------------------------|
| L                | 5 V mode (double step-up)  |
| H                | 3 V mode (3 times step-up) |

H: high-level, L: low-level, Z: high-impedance, ×: H or L

**Note 5.** When switching V<sub>CHA</sub>, standby mode must be selected ( $\overline{\text{STBY}} = \text{L}$ ).

**ABSOLUTE MAXIMUM RATINGS** ( $T_A = 25\text{ }^{\circ}\text{C}$ )

| Parameter                                                  | Symbol    | Ratings                      | Unit               |
|------------------------------------------------------------|-----------|------------------------------|--------------------|
| Supply Voltage ( $V_{CHA} = L$ )                           | $V_{CC}$  | -0.5 to +7.0                 | V                  |
| Supply Voltage ( $V_{CHA} = H$ )                           | $V_{CC}$  | -0.5 to +4.5                 | V                  |
| Driver Input Voltage                                       | $D_{IN}$  | -0.5 to $V_{CC} + 0.5$       | V                  |
| Receiver Input Voltage                                     | $R_{IN}$  | -30.0 to +30.0               | V                  |
| Control Input Voltage ( $\overline{STBY}$ , $V_{CHA}$ )    | $V_{IN}$  | -0.5 to $V_{CC} + 0.5$       | V                  |
| Driver Output Voltage                                      | $D_{OUT}$ | -25.0 to +25.0 <b>Note 6</b> | V                  |
| Receiver Output Voltage                                    | $R_{OUT}$ | -0.5 to $V_{CC} + 0.5$       | V                  |
| Input Current ( $D_{IN}$ , $\overline{STBY}$ , $V_{CHA}$ ) | $I_{IN}$  | $\pm 20.0$                   | mA                 |
| Operating Ambient Temperature                              | $T_A$     | -40 to +85                   | $^{\circ}\text{C}$ |
| Storage Temperature                                        | $T_{stg}$ | -55 to +150                  | $^{\circ}\text{C}$ |
| Total Power Dissipation                                    | $P_T$     | 0.5                          | W                  |

**Note 6.** Pulse width = 1 ms, duty = 10 % MAX.

**RECOMMENDED OPERATING CONDITIONS**

| Parameter                                                  | Symbol        | MIN. | TYP. | MAX.     | Unit               |
|------------------------------------------------------------|---------------|------|------|----------|--------------------|
| Supply Voltage ( $V_{CHA} = L$ , 5 V mode)                 | $V_{CC}$      | 4.5  | 5.0  | 5.5      | V                  |
| Supply Voltage ( $V_{CHA} = H$ , 3 V mode)                 | $V_{CC}$      | 3.0  | 3.3  | 3.6      | V                  |
| High-Level Input Voltage ( $D_{IN}$ )                      | $V_{IH}$      | 2.0  |      | $V_{CC}$ | V                  |
| Low-Level Input Voltage ( $D_{IN}$ )                       | $V_{IL}$      | 0    |      | 0.8      | V                  |
| High-Level Input Voltage ( $\overline{STBY}$ , $V_{CHA}$ ) | $V_{IH}$      | 2.4  |      | $V_{CC}$ | V                  |
| Low-Level Input Voltage ( $\overline{STBY}$ , $V_{CHA}$ )  | $V_{IL}$      | 0    |      | 0.6      | V                  |
| Receiver Input Voltage                                     | $R_{IN}$      | -30  |      | +30      | V                  |
| Operating Ambient Temperature                              | $T_A$         | -40  |      | +85      | $^{\circ}\text{C}$ |
| Capacitance of External Capacitor                          | <b>Note 7</b> | 0.33 |      | 4.7      | $\mu\text{F}$      |

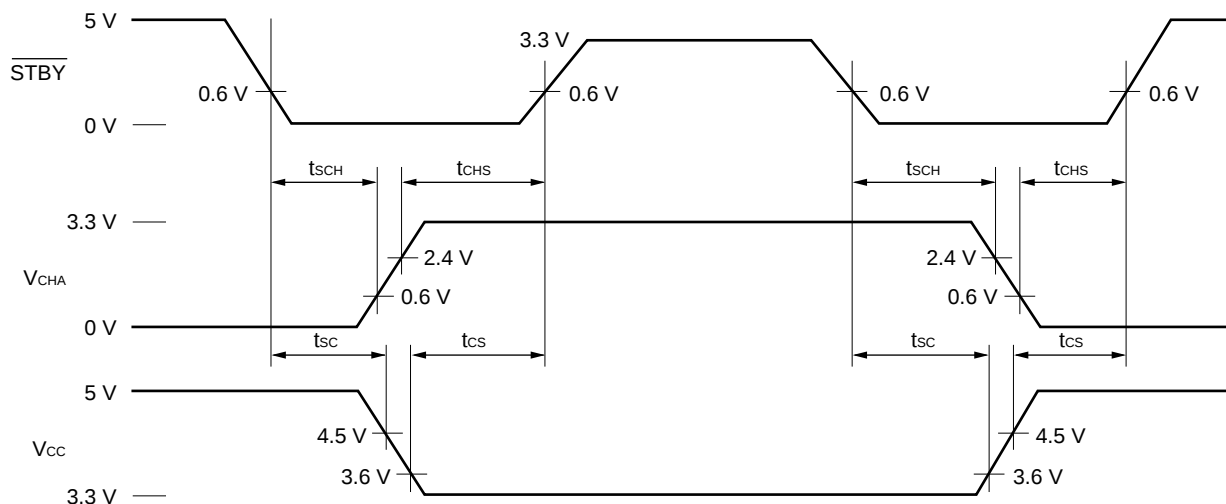
**Note 7.** In low temperature (below  $0\text{ }^{\circ}\text{C}$ ), the capacitance of electrolytic capacitor becomes lower. Therefore, set higher values when using in low temperature.

Concerning the wiring length between the capacitor and the IC, the shorter the better.

Capacitors with good frequency characteristics such as tantalum capacitors, laminated ceramic capacitors, and aluminum electrolytic capacitors for switching power supply are recommended for the external capacitors.

**ELECTRICAL SPECIFICATIONS (TOTAL)**(Unless otherwise specified,  $T_A = -40$  to  $+85$  °C,  $C_1$  to  $C_5 = 1$   $\mu$ F)

| Parameter                        | Symbol    | Conditions                                                                                                                   | MIN. | TYP. | MAX. | Unit    |
|----------------------------------|-----------|------------------------------------------------------------------------------------------------------------------------------|------|------|------|---------|
| Circuit Current                  | $I_{CC1}$ | $V_{CC} = +3.3$ V, No load, $R_{IN}$ pin OPEN, $\overline{STBY} = H$                                                         |      | 6.5  | 13   | mA      |
|                                  |           | $V_{CC} = +5.0$ V, No load, $R_{IN}$ pin OPEN, $\overline{STBY} = H$                                                         |      | 4.5  | 9    | mA      |
| Circuit Current                  | $I_{CC2}$ | $V_{CC} = +3.3$ V, $R_L = 3$ k $\Omega$ ( $D_{OUT}$ ), $D_{IN} = GND$ , $R_{IN}$ , $R_{OUT}$ pin OPEN, $\overline{STBY} = H$ |      | 19   | 24   | mA      |
|                                  |           | $V_{CC} = +5.0$ V, $R_L = 3$ k $\Omega$ ( $D_{OUT}$ ), $D_{IN} = GND$ , $R_{IN}$ , $R_{OUT}$ pin OPEN, $\overline{STBY} = H$ |      | 14   | 18   | mA      |
| Circuit Current at Standby       | $I_{CC3}$ | $V_{CC} = +3.3$ V, No load, $D_{IN}$ and $R_{IN}$ pins are OPEN, $\overline{STBY} = L$ , $T_A = 25$ °C                       |      | 1    | 3    | $\mu$ A |
|                                  |           | $V_{CC} = +3.3$ V, No load, $D_{IN}$ and $R_{IN}$ pins are OPEN, $\overline{STBY} = L$                                       |      | 5    |      | $\mu$ A |
|                                  |           | $V_{CC} = +5.0$ V, No load, $D_{IN}$ and $R_{IN}$ pins are OPEN, $\overline{STBY} = L$ , $T_A = 25$ °C                       |      | 2    | 5    | $\mu$ A |
|                                  |           | $V_{CC} = +5.0$ V, No load, $D_{IN}$ and $R_{IN}$ pins are OPEN, $\overline{STBY} = L$                                       |      | 10   |      | $\mu$ A |
| High-Level Input Voltage         | $V_{IH}$  | $V_{CC} = +3.0$ to $+5.5$ V, $\overline{STBY}$ , $V_{CHA}$ pin                                                               | 2.4  |      |      | V       |
| Low-Level Input Voltage          | $V_{IL}$  | $V_{CC} = +3.0$ to $+5.5$ V, $\overline{STBY}$ , $V_{CHA}$ pin                                                               |      |      | 0.6  | V       |
| High-Level Input Current         | $I_{IH}$  | $V_{CC} = +5.5$ V, $V_i = +5.5$ V, $\overline{STBY}$ , $V_{CHA}$ pin                                                         |      |      | 1    | $\mu$ A |
| Low-Level Input Current          | $I_{IL}$  | $V_{CC} = +5.5$ V, $V_i = 0$ V, $\overline{STBY}$ , $V_{CHA}$ pin                                                            |      |      | -1   | $\mu$ A |
| Input Capacitance                | $C_{IN}$  | Driver input and receiver input<br>$V_{CC} = +3.3$ V, for GND, $f = 1$ MHz                                                   |      |      | 10   | pF      |
|                                  |           | Driver input and receiver input<br>$V_{CC} = +5.0$ V, for GND, $f = 1$ MHz                                                   |      |      | 10   | pF      |
| $\overline{STBY} - V_{CHA}$ Time | $t_{SCH}$ | $V_{CC} = +3.0$ to $+5.5$ V, $\overline{STBY} \downarrow \rightarrow V_{CHA}$ , <b>Note 8</b>                                | 1    |      |      | $\mu$ s |
| $V_{CHA} - \overline{STBY}$ Time | $t_{CHS}$ | $V_{CC} = +3.0$ to $+5.5$ V, $V_{CHA} \rightarrow \overline{STBY} \uparrow$ , <b>Note 8</b>                                  | 1    |      |      | $\mu$ s |
| $\overline{STBY} - V_{CC}$ Time  | $t_{SC}$  | $V_{CC} = +3.0$ to $+5.5$ V, $\overline{STBY} \downarrow \rightarrow V_{CC}$ , <b>Note 8</b>                                 | 1    |      |      | $\mu$ s |
| $V_{CC} - \overline{STBY}$ Time  | $t_{CS}$  | $V_{CC} = +3.0$ to $+5.5$ V, $V_{CC} \rightarrow \overline{STBY} \uparrow$ , <b>Note 8</b>                                   | 1    |      |      | $\mu$ s |

\* The TYP. values are for reference at  $T_A = 25$  °C.**Note 8.** Measuring point

**ELECTRICAL SPECIFICATIONS (DRIVER)**(Unless otherwise specified,  $T_A = -40$  to  $+85$  °C,  $C_1$  to  $C_5 = 1$   $\mu$ F)**3 V mode** (unless otherwise specified,  $V_{CHA} = H$ ,  $V_{CC} = 3.0$  to  $3.6$  V)

| Parameter                                | Symbol                 | Conditions                                                   | MIN.      | TYP.      | MAX.     | Unit       |
|------------------------------------------|------------------------|--------------------------------------------------------------|-----------|-----------|----------|------------|
| Low-Level Input Voltage                  | $V_{IL}$               |                                                              |           |           | 0.8      | V          |
| High-Level Input Voltage                 | $V_{IH}$               |                                                              | 2.0       |           |          | V          |
| Low-Level Input Current                  | $I_{IL}$               | $V_{CC} = +3.6$ V, $V_i = 0$ V                               |           |           | -25      | $\mu$ A    |
| High-Level Input Current                 | $I_{IH}$               | $V_{CC} = +3.6$ V, $V_i = 3.6$ V                             |           |           | 1.0      | $\mu$ A    |
| Output Voltage                           | $V_{DO}$               | $V_{CC} = +3.3$ V, $R_L = \infty$ , $T_A = 25$ °C            |           | $\pm 9.5$ |          | V          |
|                                          |                        | $V_{CC} = +3.3$ V, $R_L = 3$ k $\Omega$ , $T_A = T_{opt}$    | $\pm 5.0$ | $\pm 6.0$ |          | V          |
|                                          |                        | $V_{CC} = +3.0$ V, $R_L = 3$ k $\Omega$ , $T_A = +25$ °C     | $\pm 5.0$ |           |          | V          |
| Output Short-Circuit Current             | $I_{SC}$               | $V_{CC} = +3.3$ V, for GND                                   |           |           | $\pm 40$ | mA         |
| Slew-Rate <sup>Note 9</sup>              | SR                     | $C_L = 10$ pF, $R_L = 3$ to $7$ k $\Omega$                   | 3.0       |           | 30       | V/ $\mu$ s |
|                                          |                        | $C_L = 2\ 500$ pF, $R_L = 3$ to $7$ k $\Omega$               | 3.0       |           | 30       | V/ $\mu$ s |
| Propagation Delay Time <sup>Note 9</sup> | $t_{PHL}$<br>$t_{PLH}$ | $R_L = 3$ k $\Omega$ , $C_L = 2\ 500$ pF                     |           | 2.5       |          | $\mu$ s    |
| Output Resistor                          | $R_O$                  | $V_{CC} = V_{DD} = V_{SS} = 0$ V<br>$V_{OUT} = \pm 2$ V      | 300       |           |          | $\Omega$   |
| Standby Output Transfer Time             | $t_{DAZ}$              | $R_L = 3$ k $\Omega$ , $C_L = 2\ 500$ pF, <sup>Note 10</sup> |           | 4         | 10       | $\mu$ s    |
| Standby Output Transfer Time             | $t_{DZA}$              | $R_L = 3$ k $\Omega$ , $C_L = 2\ 500$ pF, <sup>Note 10</sup> |           | 1         | 3        | ms         |
| Power-On Output Transfer Time            | $t_{PRA}$              | $R_L = 3$ k $\Omega$ , $C_L = 2\ 500$ pF, <sup>Note 11</sup> |           | 1         | 3        | ms         |

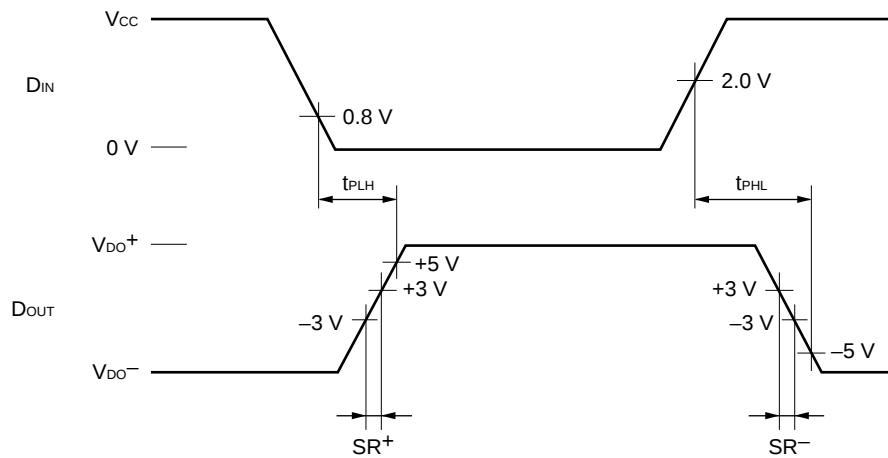
\* The TYP. values are for reference at  $T_A = 25$  °C.

**5 V mode** (Unless otherwise specified,  $V_{CHA} = L$ ,  $V_{CC} = +5.0 \text{ V} \pm 10 \%$ )

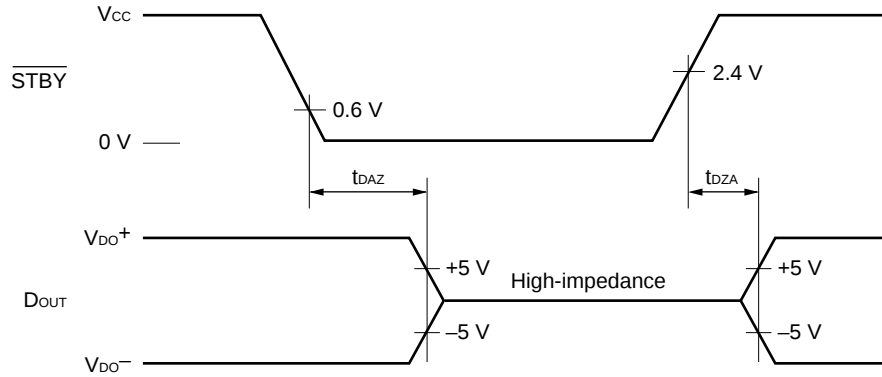
| Parameter                                | Symbol    | Conditions                                                                | MIN. | TYP. | MAX. | Unit |
|------------------------------------------|-----------|---------------------------------------------------------------------------|------|------|------|------|
| Low-Level Input Voltage                  | $V_{IL}$  |                                                                           |      |      | 0.8  | V    |
| High-Level Input Voltage                 | $V_{IH}$  |                                                                           | 2.0  |      |      | V    |
| Low-Level Input Current                  | $I_{IL}$  | $V_{CC} = +5.5 \text{ V}$ , $V_i = 0 \text{ V}$                           |      |      | -40  | μA   |
| High-Level Input Current                 | $I_{IH}$  | $V_{CC} = +5.5 \text{ V}$ , $V_i = 5.5 \text{ V}$                         |      |      | 1.0  | μA   |
| Output Voltage                           | $V_{DO}$  | $V_{CC} = +5.0 \text{ V}$ , $R_L = \infty$ , $T_A = 25^\circ\text{C}$     |      | ±9.7 |      | V    |
|                                          |           | $V_{CC} = +5.0 \text{ V}$ , $R_L = 3 \text{ k}\Omega$ , $T_A = T_{opt}$   | ±6.0 |      |      | V    |
|                                          |           | $V_{CC} = +4.5 \text{ V}$ , $R_L = 3 \text{ k}\Omega$ , $T_A = T_{opt}$   | ±5.0 |      |      | V    |
| Output Short-Circuit Current             | $I_{SC}$  | $V_{CC} = +5.0 \text{ V}$ , for GND                                       |      |      | ±40  | mA   |
| Slew-Rate <sup>Note 9</sup>              | SR        | $C_L = 10 \text{ pF}$ , $R_L = 3 \text{ to } 7 \text{ k}\Omega$           | 4.0  |      | 30   | V/μs |
|                                          |           | $C_L = 2 \text{ 500 pF}$ , $R_L = 3 \text{ to } 7 \text{ k}\Omega$        | 4.0  |      | 30   | V/μs |
| Propagation Delay Time <sup>Note 9</sup> | $t_{PHL}$ | $R_L = 3 \text{ k}\Omega$ , $C_L = 2 \text{ 500 pF}$                      |      | 2    |      | μs   |
|                                          | $t_{PLH}$ |                                                                           |      |      |      | μs   |
| Output Resistor                          | $R_O$     | $V_{CC} = V_{DD} = V_{SS} = 0 \text{ V}$<br>$V_{OUT} = \pm 2 \text{ V}$   | 300  |      |      | Ω    |
| Standby Output Transfer Time             | $t_{DAZ}$ | $R_L = 3 \text{ k}\Omega$ , $C_L = 2 \text{ 500 pF}$ , <sup>Note 10</sup> |      | 4    | 10   | μs   |
| Standby Output Transfer Time             | $t_{DZA}$ | $R_L = 3 \text{ k}\Omega$ , $C_L = 2 \text{ 500 pF}$ , <sup>Note 10</sup> |      | 0.5  | 1    | ms   |
| Power-On Output Transfer Time            | $t_{PRA}$ | $R_L = 3 \text{ k}\Omega$ , $C_L = 2 \text{ 500 pF}$ , <sup>Note 12</sup> |      | 0.5  | 1    | ms   |

\* The TYP. values are for reference at  $T_A = 25^\circ\text{C}$ .

**Note 9.** Measuring point

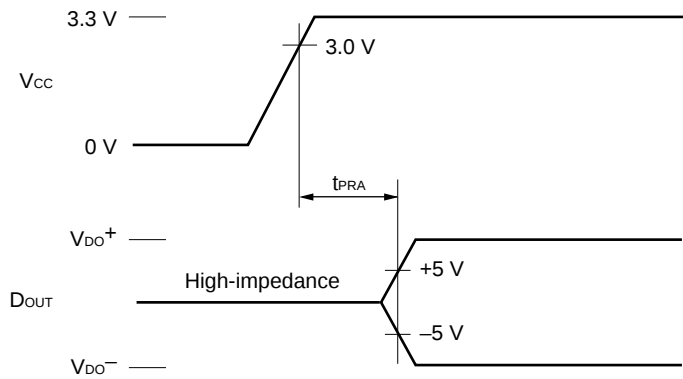


**Note 10.** Measuring point



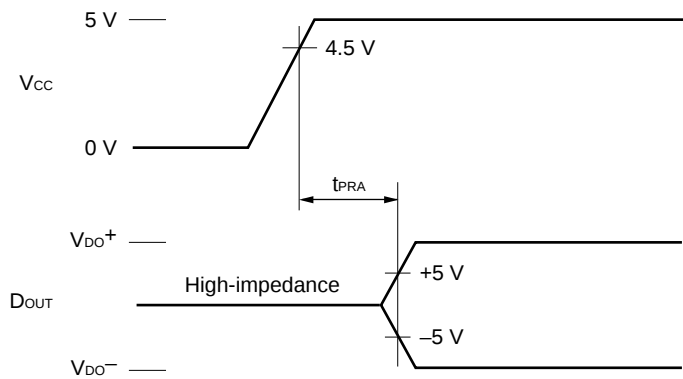
Driver outputs are indefinite during transition time ( $t_{DZA}$ ).

**Note 11.** Measuring point



Driver outputs are indefinite during transition time ( $t_{PRA}$ ).

**Note 12.** Measuring point



Driver outputs are indefinite during transition time ( $t_{PRA}$ ).

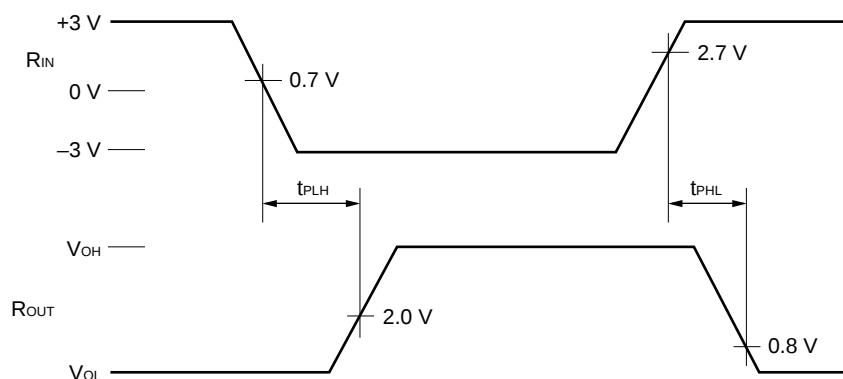
# **ELECTRICAL SPECIFICATIONS (RECEIVER)**

(Unless otherwise specified,  $V_{CC} = 3.0$  to  $5.5$  V,  $T_A = -40$  to  $+85$  °C,  $C_1$  to  $C_5 = 1$  μF)

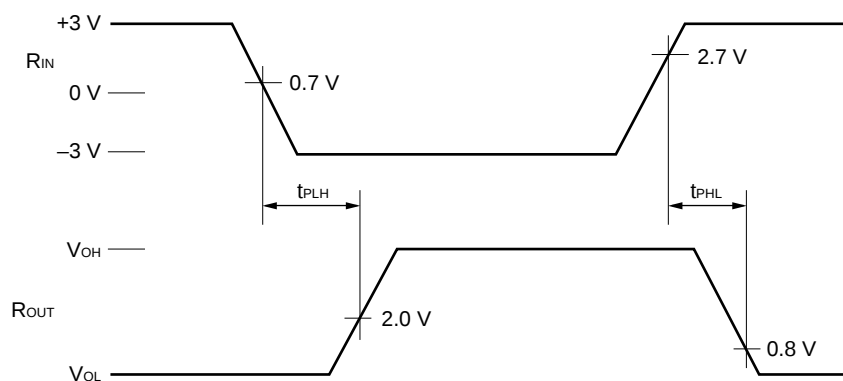
| Parameter                                           | Symbol                 | Conditions                                                                         | MIN.           | TYP. | MAX. | Unit |
|-----------------------------------------------------|------------------------|------------------------------------------------------------------------------------|----------------|------|------|------|
| Low-Level Output Voltage                            | $V_{OL1}$              | $I_{OUT} = 4$ mA, $\overline{STBY} = H$                                            |                |      | 0.4  | V    |
| High-Level Output Voltage                           | $V_{OH1}$              | $I_{OUT} = -4$ mA, $\overline{STBY} = H$                                           | $V_{CC} - 0.4$ |      |      | V    |
| Low-Level Output Voltage                            | $V_{OL2}$              | $I_{OUT} = 4$ mA, $\overline{STBY} = L$                                            |                |      | 0.5  | V    |
| High-Level Output Voltage                           | $V_{OH2}$              | $I_{OUT} = -4$ mA, $\overline{STBY} = L$                                           | $V_{CC} - 0.5$ |      |      | V    |
| Propagation Delay Time<br>( $\overline{STBY} = H$ ) | $t_{PHL}$<br>$t_{PLH}$ | $R_{IN} \rightarrow R_{OUT}$ , $C_L = 150$ pF<br>$V_{CC} = +3.0$ V, <b>Note 13</b> |                | 0.2  |      | μs   |
| Input Resistor                                      | $R_I$                  |                                                                                    | 3              | 5.5  | 7    | kΩ   |
| Input Pin Open Voltage                              | $V_{IO}$               |                                                                                    |                |      | 0.5  | V    |
| Input Threshold ( $\overline{STBY} = H$ )           | $V_{IH}$               | $V_{CC} = +3.0$ to $+5.5$ V                                                        | 1.7            | 2.3  | 2.7  | V    |
|                                                     | $V_{IL}$               | $V_{CC} = +3.0$ to $+5.5$ V                                                        | 0.7            | 1.1  | 1.7  | V    |
|                                                     | $V_H$                  | $V_{CC} = +3.0$ to $+5.5$ V (Hysteresis width)                                     | 0.5            | 1.2  | 1.8  | V    |
| Standby Output Transfer Time                        | $t_{DAH}$              | <b>Note 15</b>                                                                     |                | 0.2  | 3    | μs   |
| Standby Output Transfer Time                        | $t_{DHA}$              | $V_{CHA} = H$ (3 V mode) <b>Note 15</b>                                            |                | 0.6  | 3    | ms   |
|                                                     |                        | $V_{CHA} = L$ (5 V mode) <b>Note 15</b>                                            |                | 0.3  | 1    | ms   |
| Power-On Reset Release Time                         | $t_{PRA}$              | $V_{CHA} = H$ (3 V mode) <b>Note 16</b>                                            |                | 1    | 3    | ms   |
|                                                     |                        | $V_{CHA} = L$ (5 V mode) <b>Note 17</b>                                            |                | 0.5  | 1    | ms   |

\* The TYP. values are for reference at  $T_A = 25$  °C.

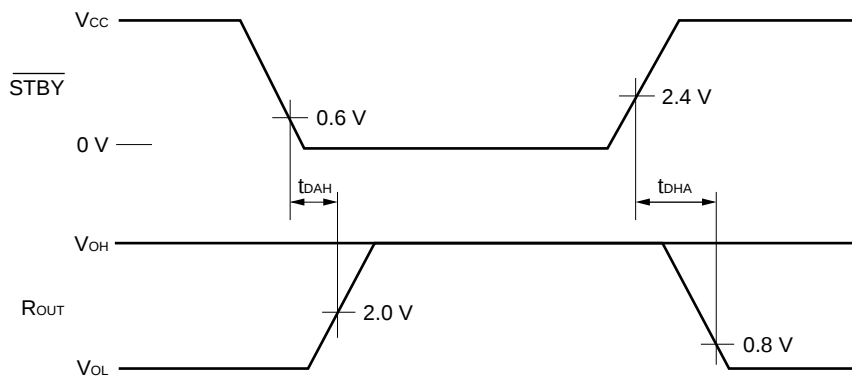
**Note 13.** Measuring point



**Note 14.** Measuring point

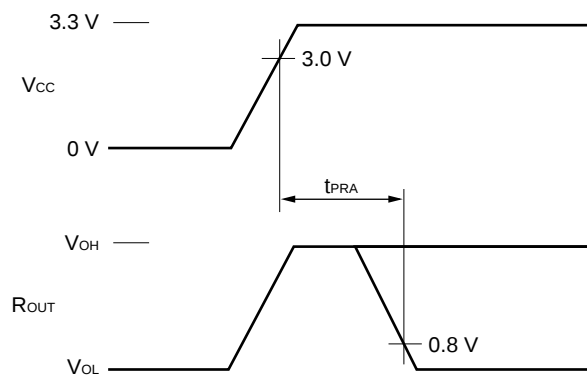


**Note 15.** Measuring point



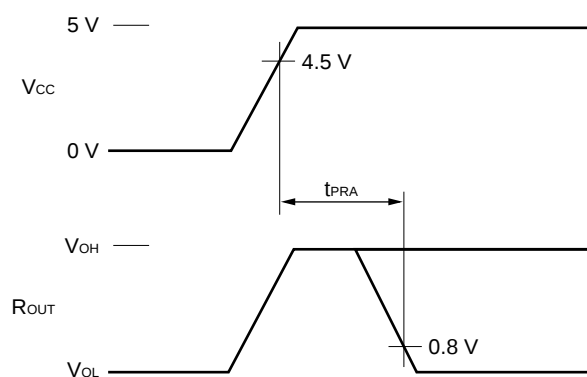
Receiver outputs are indefinite during transition time ( $t_{DHA}$ ).

**Note 16.** Measuring point



Receiver outputs are indefinite during reset release time ( $t_{PRA}$ ).

**Note 17.** Measuring point



Receiver outputs are indefinite during reset release time ( $t_{PRA}$ ).

**REFERENCE MATERIAL**

- IC PACKAGE MANUAL (C10943X)
- NEC SEMICONDUCTOR DEVICE RELIABILITY/QUALITY (IEI-1212)

## RECOMMENDED SOLDERING CONDITIONS

The following conditions (See table below) must be met when soldering this product.

Please consult with our sales offices in case other soldering process is used, or in case soldering is done under different conditions.

## TYPES OF SURFACE MOUNT DEVICE

For more details, refer to our document "SMT MANUAL" (C10535E).

### μPD4721 GS-GJG

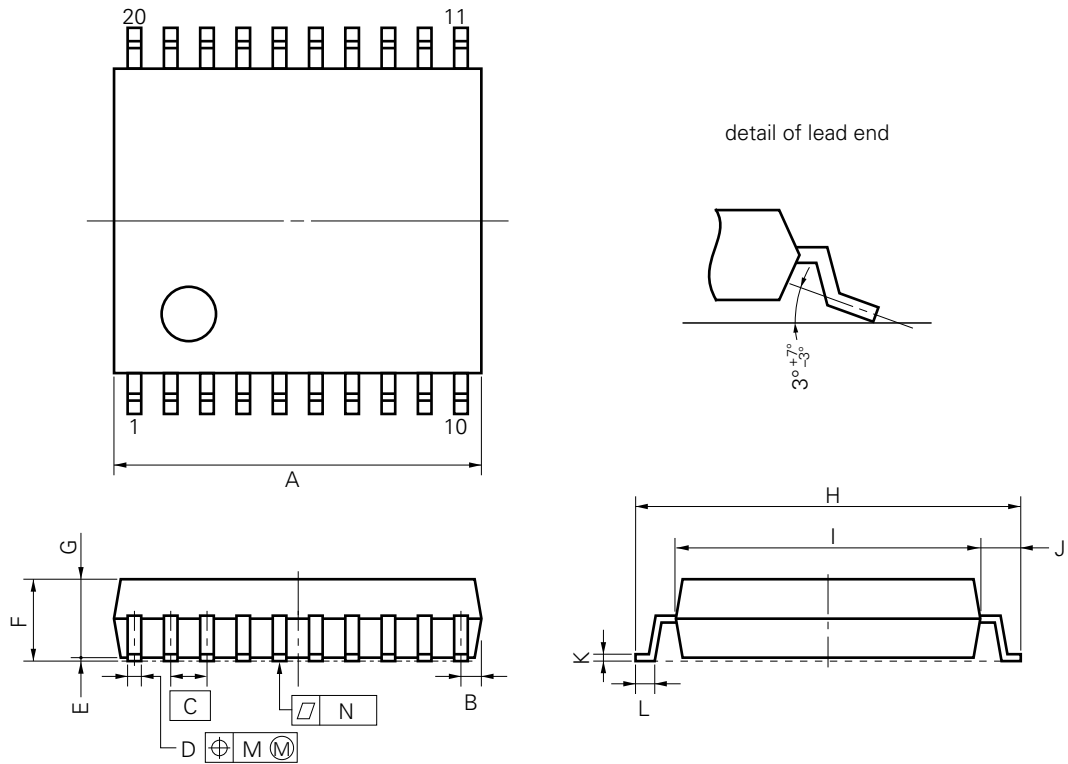
| Soldering process      | Soldering conditions                                                                                                                                                  | Symbol    |
|------------------------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------|-----------|
| Infrared ray reflow    | Peak package's surface temperature: 230 °C or below,<br>Reflow time: 30 seconds or below (210 °C or higher),<br>Number of reflow process: 2, Exposure limit*: None    | IR30-00-2 |
| VPS                    | Peak package's surface temperature: 215 °C or below,<br>Reflow time: 40 seconds or below (200 °C or higher),<br>Number of reflow process: 2,<br>Exposure limit*: None | VP15-00-2 |
| Wave soldering         | Solder Temperature: 260 °C or lower,<br>Reflow time: Within 10 sec,<br>Number of reflowprocess: 1,<br>Exposure limit*: None                                           | WS60-00-1 |
| Partial heating method | Terminal temperature: 300 °C or below,<br>Flow time: 10 seconds or below,<br>Exposure limit*: None                                                                    | ○         |

- \* Exposure limit before soldering after dry-pack package is opened.  
Storage conditions: 25 °C and relative humidity at 65 % or less.

**Note** Do not apply more than a single process at once, except for "Partial heating method"

PACKAGE DRAWINGS

20 PIN PLASTIC SHRINK SOP (300 mil)



NOTE

Each lead centerline is located within 0.12 mm (0.005 inch) of its true position (T.P.) at maximum material condition.

P20GM-65-300B-2

| ITEM | MILLIMETERS                            | INCHES                                    |
|------|----------------------------------------|-------------------------------------------|
| A    | 7.00 MAX.                              | 0.276 MAX.                                |
| B    | 0.575 MAX.                             | 0.023 MAX.                                |
| C    | 0.65 (T.P.)                            | 0.026 (T.P.)                              |
| D    | 0.30±0.10                              | 0.012 <sup>+0.004</sup> <sub>-0.005</sub> |
| E    | 0.125±0.075                            | 0.005±0.003                               |
| F    | 2.0 MAX.                               | 0.079 MAX.                                |
| G    | 1.7                                    | 0.067                                     |
| H    | 8.1±0.3                                | 0.319±0.012                               |
| I    | 6.1±0.2                                | 0.240±0.008                               |
| J    | 1.0±0.2                                | 0.039 <sup>+0.009</sup> <sub>-0.008</sub> |
| K    | 0.15 <sup>+0.10</sup> <sub>-0.05</sub> | 0.006 <sup>+0.004</sup> <sub>-0.002</sub> |
| L    | 0.5±0.2                                | 0.020 <sup>+0.008</sup> <sub>-0.009</sub> |
| M    | 0.12                                   | 0.005                                     |
| N    | 0.10                                   | 0.004                                     |

[MEMO]

[MEMO]

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NEC devices are classified into the following three quality grades:

"Standard", "Special", and "Specific". The Specific quality grade applies only to devices developed based on a customer designated "quality assurance program" for a specific application. The recommended applications of a device depend on its quality grade, as indicated below. Customers must check the quality grade of each device before using it in a particular application.

Standard: Computers, office equipment, communications equipment, test and measurement equipment, audio and visual equipment, home electronic appliances, machine tools, personal electronic equipment and industrial robots

Special: Transportation equipment (automobiles, trains, ships, etc.), traffic control systems, anti-disaster systems, anti-crime systems, safety equipment and medical equipment (not specifically designed for life support)

Specific: Aircrafts, aerospace equipment, submersible repeaters, nuclear reactor control systems, life support systems or medical equipment for life support, etc.

The quality grade of NEC devices is "Standard" unless otherwise specified in NEC's Data Sheets or Data Books. If customers intend to use NEC devices for applications other than those specified for Standard quality grade, they should contact an NEC sales representative in advance.

Anti-radioactive design is not implemented in this product.